

10/034,221

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APPLICANT: Seung Ho PYISERIAL NO: 10/034,221

WWP:rts

FILED: 12-28-01

TITLE: METHOD FOR FABRICATING A SEMICONDUCTOR
EPITAXIAL WAFER HAVING DOPED COARBON AND A SEMI
CONDUCTOR EPITAXIAL WAFER
DOCKET CH-2755 DATE: 8-29-03



Mitchell

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